Atomistic Study of Crack-Tip Cleavage to Dislocation Emission Transition in Silicon Single Crystals

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At low temperatures silicon is a brittle material that shatters catastrophically, whereas at elevated temperatures, the behavior of silicon changes drastically over a narrow temperature range and suddenly becomes ductile. This brittle-to-ductile transition has been observed in experimental studies, yet its fundamental mechanisms remain unknown. Here we report an atomistic-level study of a fundamental event in this transition, the change from brittle cleavage fracture to dislocation emission at crack tips, using the first principles based reactive force field. By solely raising the temperature, we observe an abrupt change from brittle cracking to dislocation emission from a crack within a ≈10 K temperature interval.
Here we apply the first principles based reactive force field (ReaxFF), which retains nearly the accuracy of QM, even for bond breaking events. The ReaxFF parameters are determined solely by fitting to QM data on silicon [18]. Earlier studies with ReaxFF have shown that it reproduces key experimental observations of fracture of silicon [14,15]. Material properties calculated based on the ReaxFF silicon potential, including elastic properties, fracture surface energy and dislocation properties agree well with experimental and first principles results [14,15].

Extending earlier studies, we calculate the generalized stacking fault energy curve for slip in the [112] direction on the (111) plane and find an unstable stacking fault energy $\gamma_{US} = 0.16$ eV/Å$^2$, in close agreement with density functional theory predictions of 0.13 eV/Å$^2$ [19]. We use a parallelized implementation of ReaxFF (GRASP) to perform large-scale molecular dynamics simulations [20].

Figure 1(a) depicts the three-dimensional molecular dynamics model [21,22] with a surface crack under mode I tensile loading. We consider a crystal with an initial crack serving as failure initiation point. The crack is oriented so that the $X$-$Y$-$Z$ directions are (100) $\times$ (011) $\times$ (011), creating a (100) fracture plane with initial [011] fracture direction. Our choice of the {100} crack plane orientation is motivated by our desire to create a model system in which the competition between brittle crack extension and dislocation nucleation can be studied under mode I loading. Specifically, the geometry considered here features the possibility for brittle crack extension (close to the maximum tensile or crack-opening hoop stress around a mode I crack), and a glide plane inclined by 54.7° to the cleavage plane (close to the maximum shear stress around a mode I crack at $\approx 70^\circ$). Other crystal or crack orientations do not have this feature (e.g., the {111} or {110} crack planes under mode I loading result in different planes for crack propagation and dislocation nucleation, with different Schmidt factors).

The thickness of the systems is $\approx 15$ Å, and the system consists of approximately 27 500 atoms (ReaxFF is 1–2 orders of magnitude more expensive than conventional force fields). Unlike in earlier studies (where a hybrid simulation approach was used that combined a ReaxFF with a Tersoff potential) [14,15] the entire domain is modeled using ReaxFF. The system size is 196 Å $\times$ 184 Å $\times$ 15 Å with periodic boundary conditions in $X$ and $Z$ directions, with initial crack length 40 Å (one fifth of the sample size in the $Y$ direction). Additional simulations with much larger system sizes have been carried out, and similar results as reported here are observed (in thicker systems we observe the nucleation of dislocation loops at the crack tip). We simulate a canonical ensemble ($NVT$) with temperature control using a Berendsen thermostat [23]. To apply load, we continuously strain the system under mode I tensile load, by displacing the boundaries [16] at a strain rate of $1 \times 10^9$ s$^{-1}$. The crack-tip position is determined by finding the surface atom with maximum $Y$ position in the interior of a search region inside the slab. Velocities of the crack tip are calculated by averaging the time derivative of the crack-tip position. Visualizations are performed using the Visual Molecular Dynamics software [24].

We carry out twelve computational experiments at temperatures from 200 to 1200 K, with exactly the same initial and boundary conditions (other than temperature). Figure 1(b) shows the results of the crack-tip position over time for all temperatures. We find that the results fall in two types of behavior, and that there exists a sudden change in the behavior as the temperature is increased beyond a critical temperature. At the lowest temperatures (200 to 500 K) the system behaves in a perfectly brittle fashion where the crack propagates in steps along the usual {111} fracture surface, as known from experiment and other simulations. The crack speed quickly approaches 2–3 km $\cdot$ s$^{-1}$ after fracture initiation, in agreement with earlier work [13,15] and experiment [25]. To test the applicability of the Griffith criterion for brittle fracture, the critical stress intensity factor $K_c$ is calculated from the simulations to be $\approx 0.83$ MPa$\sqrt{\text{m}}$ (500 K). Based on the surface energy the Griffith fracture toughness is 0.82 MPa$\sqrt{\text{m}}$, in good agreement.

From Fig. 1(b) it can be seen that as the temperature is increased up to 800 K, small steps of crack arrest occur along the crack pathway (here, crack arrest refers to a complete stop of crack motion for a few picoseconds) followed by reinitiation of the crack. The overall crack path is brittle, without occurrence of dislocations. As the temperature is increased further beyond 800 K, the crack arrest and reinitiation behavior gradually becomes more evident and features larger arrest times, until suddenly, at a critical temperature of about 890 K, the crack comes to a complete stop in the middle of the sample, without any further crack propagation [Figs. 1(b) and 1(c)].

The analysis of the atomistic structure during crack extension through a slip vector analysis [26] explains this observation. We consider two representative cases from either side of the critical temperature. Figure 2(a) displays snapshots of crack dynamics at 200 K, showing “clean” brittle fracture through generation of almost perfectly flat atomic surfaces. The analysis at 1200 K shown in Fig. 2(b) reveals the nucleation of a partial dislocation from the crack tip. Once a 90° partial dislocation is emitted on a {111} glide plane the crack stops. We find that the slip direction is [211] and the slip vector is 2.3 Å, in good accordance with the partial Burgers vector on that glide plane. These results reveal a very sharp transition from brittle cleavage fracture to dislocation emission behavior within an extremely narrow temperature regime of $\approx 10$ K.

The mechanism for the transition from the cleavage fracture to dislocation emission behavior can be explained based on atomic mechanisms at the crack tip. Figures 3(a)}
and 3(b) show the brittle fracture process (200 K), which proceeds through small fracture steps (nanocracks) on \{111\} planes. These nanocracks, consisting of single bond breaking events on alternating \{111\} planes intersecting at the crack tip, enable the brittle crack to effectively move forward in the (011) direction. In the brittle regime, for any crack extension there is a competition between the energetically less favorable \{100\} plane, which has a higher surface energy, and the \{111\} planes, which intersect at 54.7° with respect to the \{100\} plane. The tensile stresses that act on the \{100\} plane are decisive for the crack to remain on this plane. Nevertheless, crack-tip crack propagation along the \{111\} planes takes place locally, in agreement with earlier findings that have suggested that the \{111\} is a preferred fracture plane [27].

As the critical temperature is approached, crack-tip blunting dominates and is accompanied by changes in the perfect hexagonal ring structure at the crack tip. Bond rotations at the crack tip lead to the formation of new covalent bond structures that differ from the typical 6-membered hexagonal rings. These less structured, disordered zones extend over \approx 10 Å. Figures 3(c)–3(e) show a detailed analysis at 1200 K where a ledge has formed and the crack has diverted along a \{111\} cleavage plane.

The emergence of these structural changes at the crack tip has major implications on the behavior of the crack. As the crack tip becomes wider, the stress required for brittle fracture increases, because of the lowering of the crack-opening stress intensity at a blunt tip [15,28]. Moreover, blunting induces a change of the crack-tip shape, as it facilitates a rotation of the crack front to align with \{111\} planes, leading to the formation of a small \{111\} cleavage ledge at the crack tip. At the ledge tip, the loading now exhibits mode II shear components oriented at approximately 55° with respect to the \{100\} plane. It has been shown theoretically that even very small amounts of shear loading (\approx 10% of tensile load) can lead to emission of dislocations [29]. This suggests that the change of the stress field due to ledges formation may indeed induce the nucleation of dislocations. Notably, in contrast to experimental observations of the presence of ledges after the generation of dislocations [10,30], or ledges due to surface irregularities caused by river patterns, microstructural or impurity distribution variations, the ledges observed in our study are intrinsically formed by the crack-tip blunting and rotation mechanisms, prior to any dislocation nucleation. The mechanism is summarized in Fig. 4.

Our results provide an atomistic-scale view of changes in crack-tip mechanisms from cleavage fracture to dislocation emission in silicon under changes in the temperature. Our fully atomistic approach offers insight to crack-tip mechanisms that is currently missing from theoretical analyses of dislocation emission [31–34]. Our simulations reproduce the typical sudden change of key crack-tip mechanisms under slight temperature variations. However, while our study may have revealed one possible mechanism associated with the BDT, more studies need to be carried out to probe the behavior of the system under strain rate variations. This is critical to make a rigorous link to BDT mechanisms seen in experiment, which are performed at lower rates.

Moreover, our analysis focused solely on events at a single crack tip, and on mechanisms associated with crack extension or dislocation nucleation and thus does not yet capture the full complexity of the BDT. Still, the mechanisms obtained from this work could be combined with continuum dislocation mobility models using a coupled multiscale modeling approach to study the whole process.
BDT over a broad entire range of temperatures, strain rates, and length scales. Reaction pathway analyses [35–37] of formation of disordered zones and ledges uncovered in this study could be undertaken in order to obtain activation energy barriers for these events. This information, combined with critical dislocation loop nucleation barriers [38] under the influence of crack-tip ledges and disordered zones, could provide quantitative energetics required to simulate dislocation nucleation events in large-scale models.

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